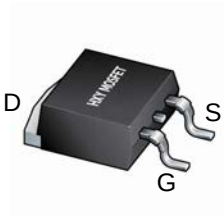
Description

The RJE0605JPD-00#J3 uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.



TO252-2L

General Features

V_{DS} =- 60V,I_D =-20A

$R_{DS(ON)}$ < 72mΩ @ V_{GS}=-10V

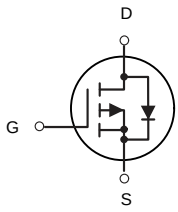
$R_{DS(ON)}$ < 100mΩ @ V_{GS}=-4.5V

Application

PWM applications

Load switch

Power management



P-Channel MOSFET

Package Marking and Ordering Information

Product ID	Pack	Brand	Qty(PCS)
RJE0605JPD-00#J3	TO252-2L	HXY MOSFET	2500

Absolute Maximum Ratings (TA=25℃ unless otherwise noted)

Symbol	Parameter	Limit	Unit
VDS	Drain-Source Voltage	-60	V
VGS	Gate-Source Voltage	±20	V
I_D(25°C)	Drain Current-Continuous@ Current-Pulsed (Note 1)	-20	A
I_D(70°C)		-15	A
IDM		-48	A
P_D	Maximum Power Dissipation	40	W
TJ,TSTG	Operating Junction and Storage Temperature Range	-55 To 175	°C
$R_{\theta JA}$	Thermal Resistance,Junction-to-Ambient (Note 2)	20	°C/W

Electrical Charcteristics (TA=25℃ unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS}=0V I_D=-250μA	-60			V
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS}=-48V,V_{GS}=0V			-1	μA
Gate-Body Leakage Current	I_{GSS}	V_{GS}=±20V,V_{DS}=0V			±100	nA
Gate Threshold Voltage	$V_{GS(th)}$	V_{DS}=V_{GS},I_D=-250μA	-1	-1.8	-2.5	V
Drain-Source On-State Resistance	$R_{DS(ON)}$	V_{GS}=-10V, I_D=-10A		64	72	mΩ
		V_{GS}=-4.5V, I_D=-10A		90	100	mΩ
Forward Transconductance	g_{FS}	V_{DS}=-5V,I_D=-20A	5			S
Input Capacitance	C_{lss}	V_{DS}=-30V,V_{GS}=0V, F=1.0MHz		2460		PF
Output Capacitance	C_{oss}			220		PF
Reverse Transfer Capacitance	C_{rss}			155		PF
Turn-on Delay Time	$t_{d(on)}$	V_{DS}=-30V,V_{GS}=-10V,R_{GEN}=3Ω I_D=1A		14		nS
Turn-on Rise Time	t_r			20		nS
Turn-Off Delay Time	$t_{d(off)}$			40		nS
Turn-Off Fall Time	t_f			19		nS
Total Gate Charge	Q_g	V_{DS}=-30V,I_D=-20A,V_{GS}=-10V		48		nC
Gate-Source Charge	Q_{gs}			11		nC
Gate-Drain Charge	Q_{gd}			10		nC
Body Diode Reverse Recovery Time	T_{rr}	I_F=-20A, dI/dt=100A/μs		40		nS
Body Diode Reverse Recovery Charge	Q_{rr}			56		nC
Diode Forward Voltage (Note 3)	V_{SD}	V_{GS}=0V,I_S=-1A		-0.72	-1	V

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on 1in^2 FR4 Board, t ≤ 10 sec.

3. Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 2%.

4. Guaranteed by design, not subject to production testing.

Typical Electrical And Thermal Characteristics

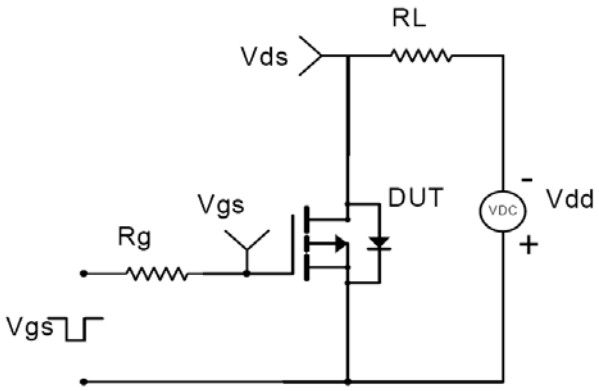


Figure 1:Switching Test Circuit

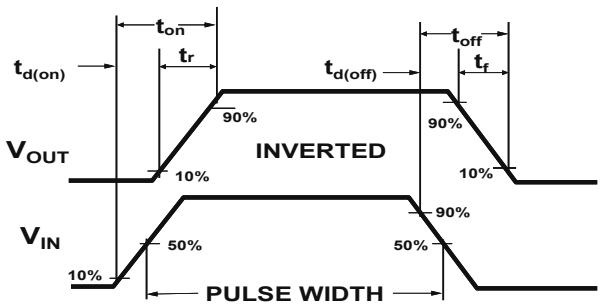


Figure 2:Switching Waveforms

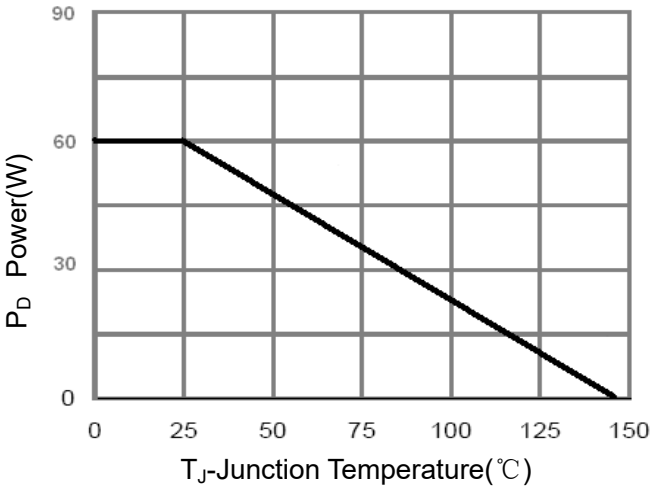


Figure 3 Power Dissipation

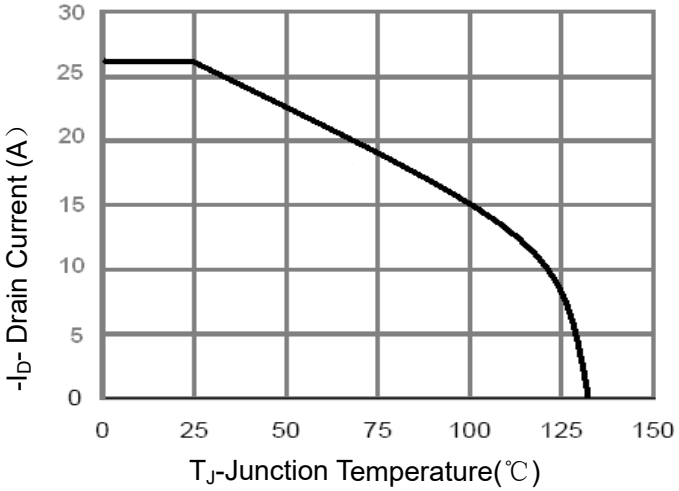


Figure 4 Drain Current

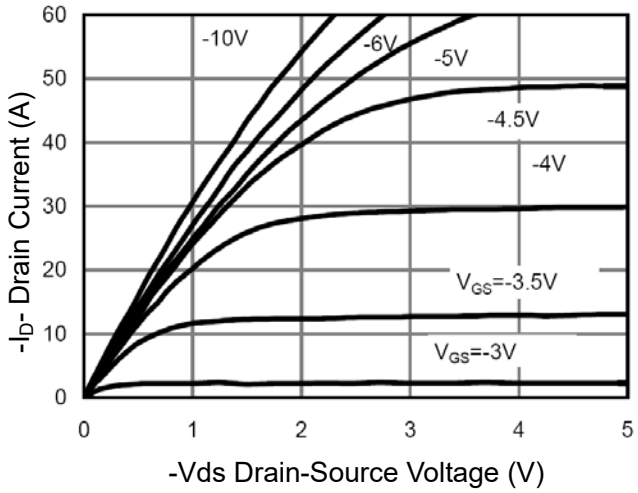


Figure 5 Output CHARACTERISTICS

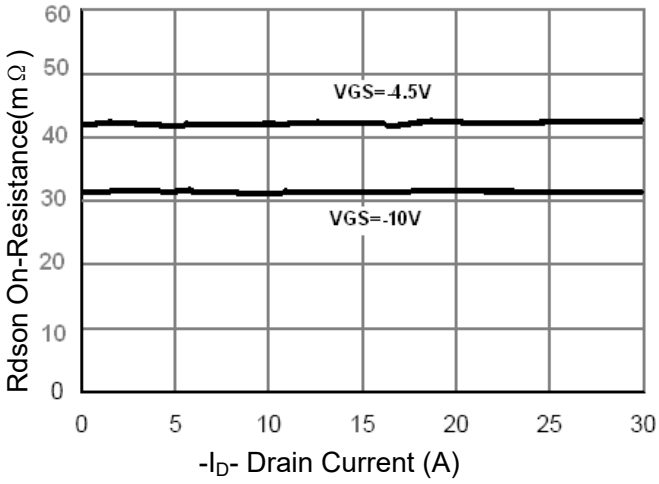


Figure 6 Drain-Source On-Resistance

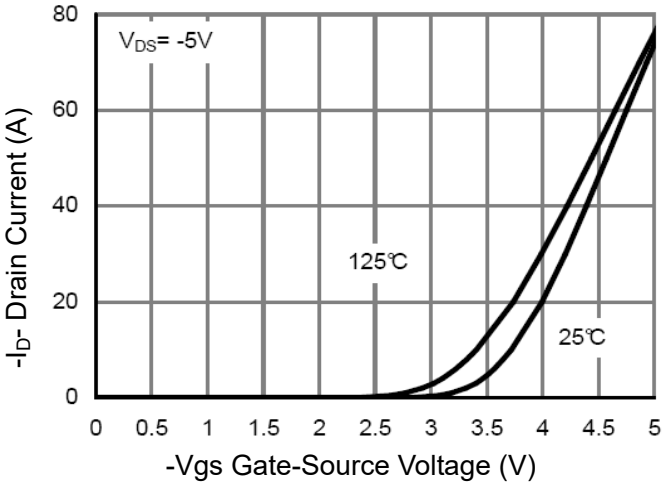


Figure 7 Transfer Characteristics

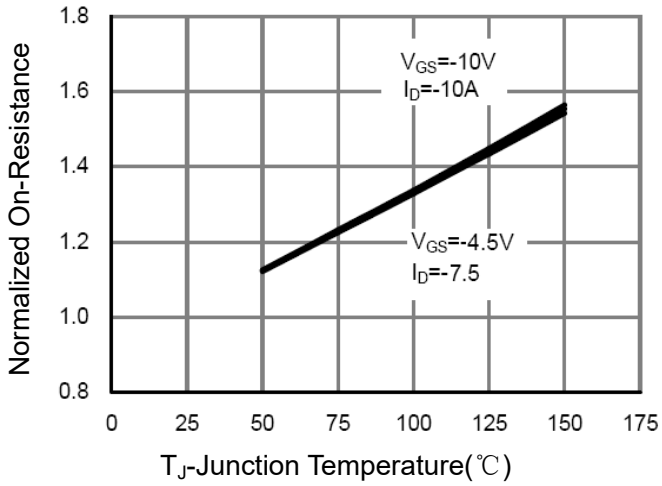


Figure 8 Drain-Source On-Resistance

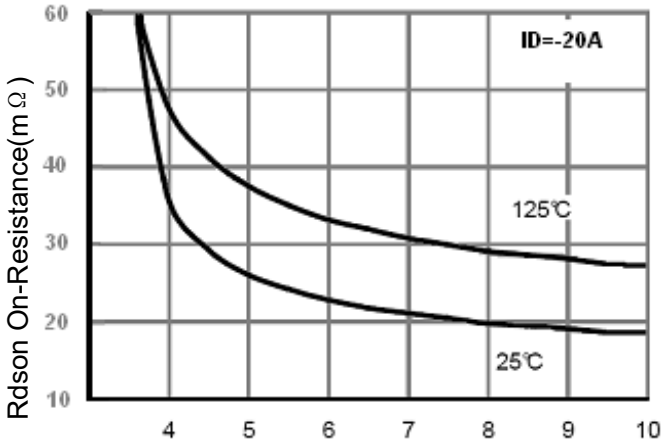


Figure 9 Rdson vs Vgs

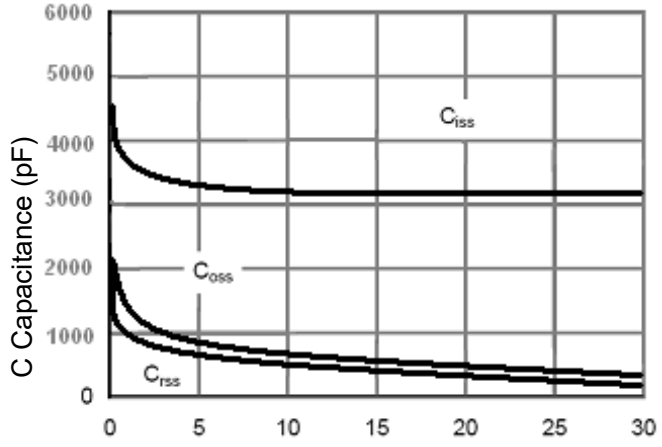


Figure 10 Capacitance vs Vds

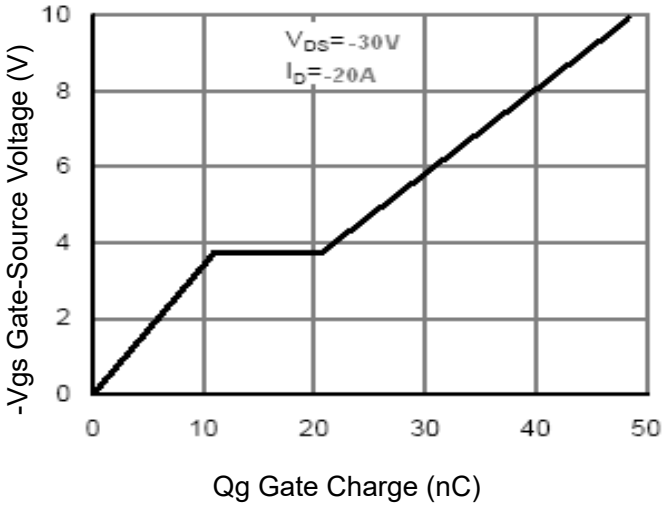


Figure 11 Gate Charge

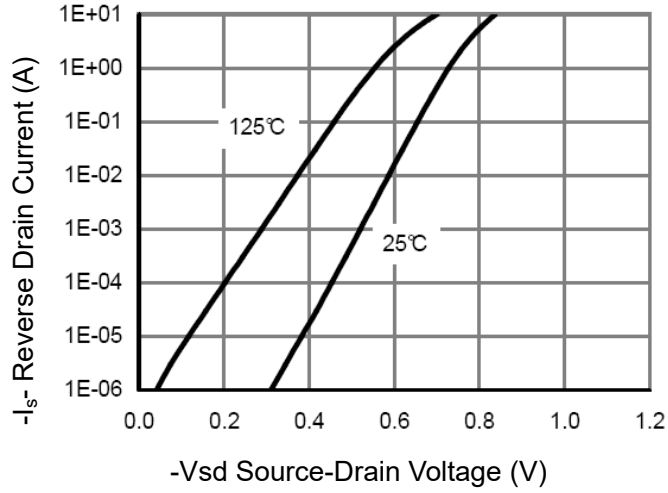


Figure 12 Source- Drain Diode Forward

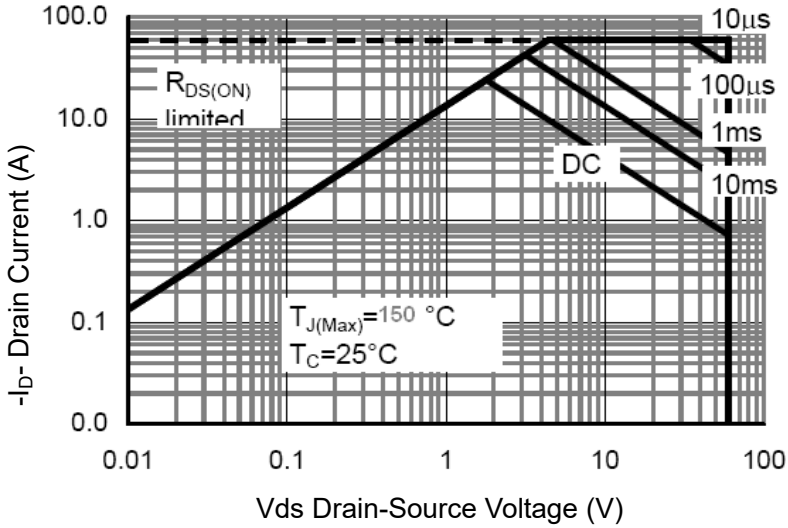


Figure 13 Safe Operation Area

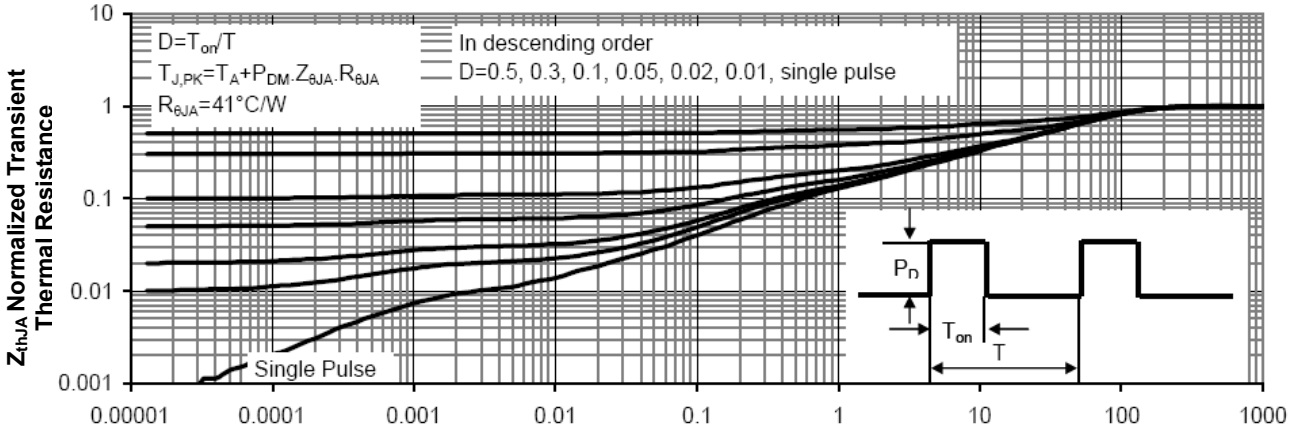
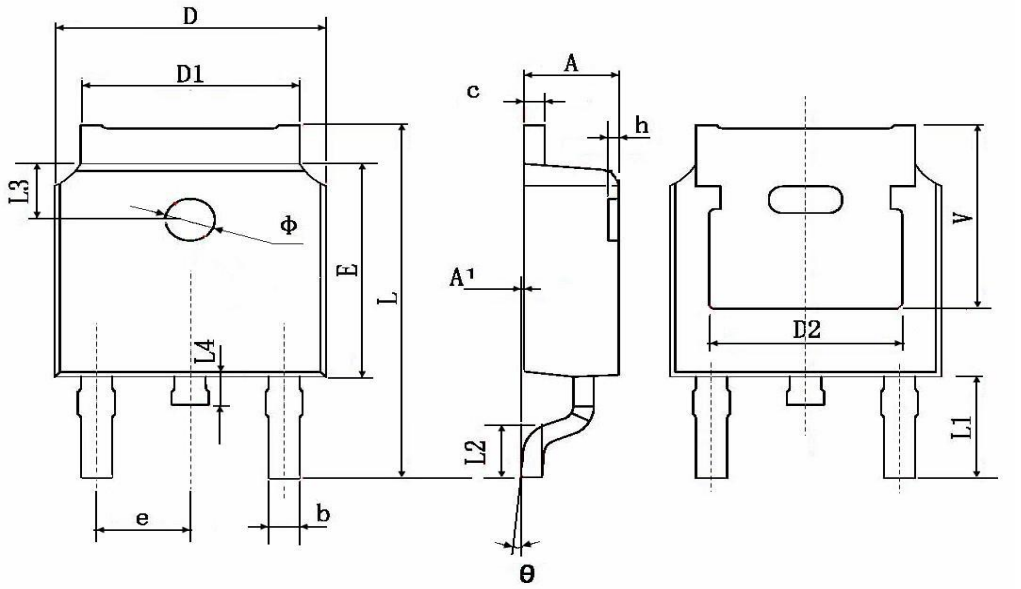


Figure 14 Normalized Maximum Transient Thermal Impedance

TO252-2L Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	2.200	2.400	0.087	0.094
A1	0.000	0.127	0.000	0.005
b	0.660	0.860	0.026	0.034
c	0.460	0.580	0.018	0.023
D	6.500	6.700	0.256	0.264
D1	5.100	5.460	0.201	0.215
D2	4.830 TYP.		0.190 TYP.	
E	6.000	6.200	0.236	0.244
e	2.186	2.386	0.086	0.094
L	9.800	10.400	0.386	0.409
L1	2.900 TYP.		0.114 TYP.	
L2	1.400	1.700	0.055	0.067
L3	1.600 TYP.		0.063 TYP.	
L4	0.600	1.000	0.024	0.039
Φ	1.100	1.300	0.043	0.051
θ	0°	8°	0°	8°
h	0.000	0.300	0.000	0.012
V	5.350 TYP.		0.211 TYP.	

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ZXMN2F34FH DMP3160L HCEZ36V,L3F SMF33CA DMP3130LQ-7 HAQ4024-01FTG-C HNUP2115LT3G
IRFH8318TRPBF HGSOT24C-HG3-08 HPTVSUC3D5VB RRR030P03TL RZR025P01TL AOTL66912
DMN3042L HGSOT36C-HG3-08 HLY323BC1524L HUCD32C05L01-AT AON6362 HC3D02120E
HGSOT36C-E3-08 DMN2041L-7 HESD5V0D5B-TP HGSOT36C-HE3-08 HUDD32C12L01